		Search Text	DB	Time stamp 2002/06/03 08:43
Number	Hits 65	1111057 (0121) CCIS) Or	USPAT;	2002/06/03 08:43
	65	(("257/288").CCLS.) or (("257/327").CCLS.)	US-PGPUB;	
		or (("257/335").CCLS.) or	EPO; JPO;	
		//#257/230"\ CCLS.) Or	DERWENT;	
		(("257/355").CCLS.)) and transistor and	IBM_TDB	
		deplotion add mode		2002/06/02 18:26
ŀ	0	("dmos.ti,ab. and buried.ti,ab. and	USPAT;	2002/00/02 10:20
	0	depletion.ti,ab.").PN.	US-PGPUB;	
	ļ	dopiosition	EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/01/06 15:09
	3	dmos.ti,ab. and buried.ti,ab. and	USPAT;	2002/01/00 13:03
		depletion.ti,ab.	US-PGPUB;	
	<u> </u>	1	EPO; JPO;	
			DERWENT; IBM TDB	
			USPAT;	2002/01/06 15:02
	2	jp-02122672\$-\$.did.	US-PGPUB;	2002,01,01
	_	j.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
			USPAT;	2002/01/06 15:02
	2	jp-08321606\$-\$.did.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
			USPAT;	2002/01/06 15:0
	78	dmos.ti,ab. and buried.ti,ab.	US-PGPUB;	
			EPO; JPO;	1
			DERWENT;	
			1	
			IBM_TDB USPAT	2002/01/06 15:1
	19	dmos.ti,ab. and buried.ti,ab.	USPAT	2002/01/06 15:1
_	0	dmos tilab, and buried.ti,ab. and	OSPAI	2002,01,00 20.1
		withstand adi2 voltage.ti,ab.	TICDAT	2002/01/06 15:2
-	1	dmos.ti,ab. and buried.ti,ab. and	USPAT	2002/01/00 10:2
		withstand adj2 voltage	HCDAM.	2002/01/06 15:3
_	500		USPAT;	2002/01/00 2011
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
			USPAT;	2002/06/02 18:3
_	13	((("257/213").CCLS.) or		2002, 01, 1
		(("257/288").CCLS.) or (("25//32/").CCLS.)	EPO; JPO;	
		or (("257/335").CCLS.) or	DERWENT;	
		(("257/339").CCLS.) or	IBM_TDB	
		(("257/355").CCLS.)) and buried.cim. and	1011_100	
		(dmos or dmosfet).ti,ab.	USPAT;	2002/01/06 15:
_	74	((("257/213").CCLS.) or		
		(("257/288").CCLS.) or (("257/327").CCLS.)	EPO; JPO;	
		or (("257/335").CCLS.) or	DERWENT;	
		(("257/339").CCLS.) or	IBM TDB	
		(("257/355").CCLS.)) and buried.clm. and	121122	
		/dmos or dmosfet or fet or fleid adj		
		officet add transistor or mos or mosiet or		
		nmso or nmosfet or pmos or pmosiet).tl, ab	USPAT;	2002/01/06 17:
_	75	= ///"257/213"\ CCLS.\ or	OPINI	2002, 02, 00
		(("257/288").CCLS.) or (("25//32/").CCLS.	EPO; JPO;	
		or (("257/335").CCLS.) or	DERWENT;	
		1 / / U 2 5 7 / 3 3 Q U C C T . S	IBM TDB	
		(/#257/355") CCLS.)) and burled.Clm. and	I DM_I DD	V 1
		/dmag or dmosfet or fet or Ileia au		
	1	refeat add transistor or mos or moster or		
		nmos or nmosfet or pmos or pmosiet). Li, ab	•	2002/01/06 18:
_		1 5742087.pn. and depletion	OSIMI	1
			US-PGPUB; EPO; JPO;	
	Ì		DERWENT; IBM TDB	
	1	t .	I TOM I DO	1



				105 105 10
	72	(first adj buried and second adj	USPAT;	2002/01/06 18:13
		buried).clm. and (breakdown adj voltage or	US-PGPUB; EPO; JPO;	
		withstand adj voltage)	DERWENT;	
			IBM_TDB	
	18	(first adj buried and second adj	USPAT;	2002/01/06 18:27
_	10	buried) clm. and (breakdown adj voltage or	US-PGPUB;	
		withstand adj voltage) and impurity and	EPO; JPO;	
		switching	DERWENT;	
		2 . 14 1	<pre>IBM_TDB USPAT;</pre>	2002/01/07 10:32
-	122	(first adj buried and second adj buried) and (breakdown adj voltage or withstand	US-PGPUB;	2002/01/3/ 10:02
		and (breakdown adj voitage of withstand adj voltage)	EPO; JPO;	
		adj voitage,	DERWENT;	
			IBM_TDB	2222/01/06/20:00
_	987	switching near10 diode and 257/\$6.ccls.	USPAT;	2002/01/06 20:09
			US-PGPUB; EPO; JPO;	*
			DERWENT;	1
			IBM TDB	
	987	(switching near10 diode) and 257/\$6.ccls.	USPAT;	2002/01/06 20:09
_	987	(Switching heart) aroas, and 2007, to the	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/01/06 20:09
-	203	(switching adj2 diode) and 257/\$6.ccls.	USPAT; US-PGPUB;	2002/01/06 20:09
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	38	(switching adj2 diode).ti,ab. and	USPAT;	2002/01/06 20:21
-	30	257/\$6.ccls.	US-PGPUB;	
		2377 40103201	EPO; JPO;	
			DERWENT;	
			IBM_TDB USPAT;	2002/01/06 20:22
-	0		US-PGPUB;	2002/01/00 20:22
		257/\$6.ccls. and galbiati.in.	EPO; JPO;	
			DERWENT;	1
			IBM_TDB	1
_	0	(switching adj2 diode).ti,ab. and	USPAT;	2002/01/06 20:23
		257/\$6.ccls. and ludikhuize.in.	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
	C1	fifth adj impurity.clm. and 257/\$6.ccls.	USPAT;	2002/01/07 08:16
_	01	itten aug impurity.cim. una 20.740.0020.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/01/07 08:17
-	18		USPAT; US-PGPUB;	2002/01/0/ 00:1/
		and switching	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	43	(first adj impurity near12 second adj	USPAT;	2002/01/07 10:54
		impurity) near12 surround\$3	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
		((first adj impurity near12 second adj	USPAT;	2002/01/07 11:42
-	6	<pre>((first adj impurity near12 second adj impurity) near12 surround\$3) and switching</pre>	US-PGPUB;	
		Imputitely neutra buttounayo, and analysis	EPO; JPO;	
			DERWENT;	İ
			IBM_TDB	0000/01/07 11 13
-	12	(buried adj region near10 gap) and	USPAT;	2002/01/07 11:43
		(257/\$6.ccls. or 438/\$6.ccls.)	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM_TDB	

-	3	5874767.pn.	USPAT; US-PGPUB;	2002/01/07 14:28
			EPO; JPO; DERWENT;	
			IBM TDB	ļ
-	298	((slit or gap or opening) near10 buried) and (withstand or breakdown) adj voltage	USPĀT; US-PGPUB;	2002/01/07 14:31
		and (withstand of breakdown, day torough	EPO; JPO; DERWENT;	
			IBM_TDB	
-	273	((slit or gap or opening) near10 buried) and (withstand or breakdown) adj voltage	USPAT; US-PGPUB;	2002/01/07 14:33
		and (438/\$6.ccls. or 257/\$6.ccls.)	EPO; JPO; DERWENT;	
	5.0	(/-lit as man) mage 10 humind) and	IBM_TDB USPAT;	2002/01/07 14:40
-	52	((slit or gap) near10 buried) and (withstand or breakdown) adj voltage and	US-PGPUB;	2002/01/01 11110
		(438/\$6.ccls. or 257/\$6.ccls.)	EPO; JPO; DERWENT;	
_	14	((slit or gap) near10 buried adj2 (region	IBM_TDB USPAT;	2002/01/07 14:45
		or layer)) and (withstand or breakdown) adj voltage and (438/\$6.ccls. or	US-PGPUB; EPO; JPO;	
		257/\$6.ccls.)	DERWENT; IBM TDB	
-	14	((slit or gap) near10 buried adj2	USPAT;	2002/01/07 15:32
		("regions" or "layers")) and (withstand or breakdown) adj voltage and (438/\$6.ccls.	US-PGPUB; EPO; JPO;	
		or 257/\$6.ccls.)	DERWENT; IBM TDB	
-	382	(257/653).CCLS.	USPAT; US-PGPUB;	2002/01/07 15:32
			EPO; JPO;	
			DERWENT; IBM TDB	
-	101	(257/654).CCLS.	USPAT; US-PGPUB;	2002/01/07 15:32
			EPO; JPO; DERWENT;	
			IBM_TDB USPAT;	2002/01/07 15:33
-	7	((("257/653").CCLS.) or (("257/654").CCLS.)) and buried and (slit	US-PGPUB;	2002/01/07 13:33
		or gap)	EPO; JPO; DERWENT;	
_	472	(("257/653").CCLS.) or (("257/654").CCLS.)	IBM_TDB USPAT;	2002/01/07 17:19
	1.2	(US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	
-	220	buried adj2 ("regions" or "layers") same	USPAT;	2002/01/07 16:26
		(recess\$3 or indent\$5 or gap)	US-PGPUB; EPO; JPO;	
			DERWENT; IBM_TDB	
-	70	buried adj2 ("regions" or "layers") near12 (recess\$3 or indent\$5 or gap)	USPAT; US-PGPUB;	2002/01/07 16:26
		(23335575 52 233675 52 3457	EPO; JPO; DERWENT;	
			IBM_TDB	2002/01/07 16:27
1-	20	(recess\$3 or indent\$5 or gap) and	USPAT; US-PGPUB;	2002/01/07 16:27
		257/\$6.ccls.	EPO; JPO; DERWENT;	
_	209	(("257/653").CCLS.) or (("257/654").CCLS.)	IBM_TDB JPO;	2002/01/07 16:30
	209	((257,005 7.0025.7 02 ((257,052 7.0025.7	DERWENT; IBM TDB	
		(("257/653").CCLS.) or (("257/654").CCLS.)	JPO_	2002/01/07 16:30 2002/01/07 16:33
-	22	((("257/653").CCLS.) or (("257/654").CCLS.)) and buried	JPO	2002/01/07 10.33

	1 1	((("257/653").CCLS.) or	JPO	2002/01/07 16:33
_	_	(("257/654").CCLS.)) and buried and (slit		
-	27	or gap or opening) ((("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.)	USPAT; US-PGPUB;	2002/01/07 17:12
		or (("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)) and (buried adj2	EPO; JPO; DERWENT; IBM_TDB	
		(region or layer) same (gap or opening or slit))		
-	16	((("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.) or (("257/335").CCLS.) or (("257/339").CCLS.) or	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/01/07 17:12
		(("257/355").CCLS.)) and (buried same thickness same increase)	IBM_TDB	2002/01/07 17:20
-	21	((("257/653").CCLS.) or (("257/654").CCLS.)) and (buried same thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	:
_	5	((("257/653").CCLS.) or	IBM_TDB USPAT;	2002/01/07 17:22
		(("257/654").CCLS.)) and (buried same thickness same (greater or increase\$1))	US-PGPUB; EPO; JPO; DERWENT;	
-	0	5629558.PN. and (thick\$4 same buried)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/01/07 17:22
			DERWENT; IBM_TDB	47.00
-	1	5629558.PN. and thick\$4	USPAT; US-PGPUB; EPO; JPO;	2002/01/07 17:22
		(,HAE7/200H) CCIS	DERWENT; IBM_TDB USPAT;	2002/01/07 18:50
-	3222	(("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.) or (("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)	US-PGPUB; EPO; JPO; DERWENT;	
-	2		IBM_TDB USPAT; US-PGPUB;	2002/01/07 18:52
			EPO; JPO; DERWENT; IBM TDB	
_	2	6177712.pn.	USPAT; US-PGPUB; EPO; JPO;	2002/01/07 19:45
	15	(lateral adj2 field adj effect and	DERWENT; IBM_TDB USPAT;	2002/01/07 20:35
	15	switching).ti,ab.	US-PGPUB; EPO; JPO; DERWENT;	
-	5	(("5629558") or ("5940700") or ("5874767") or ("4485392") or ("6127695")).PN.	IBM_TDB USPAT	2002/01/07 20:36
_	398		USPAT; US-PGPUB; EPO; JPO;	2002/06/02 18:34
_	733	(257/288).CCLS.	DERWENT; IBM_TDB USPAT; US-PGPUB;	2002/06/02 18:35
			EPO; JPO; DERWENT; IBM TDB	

<u> </u>	362	(257/327).CCLS.	USPAT; US-PGPUB;	2002/06/02 18:35
			EPO; JPO;	
			DERWENT;	
			IBM_TDB USPAT;	2002/06/02 18:35
-	456	(257/339).CCLS.	US-PGPUB;	2002/00/02 10.33
			EPO; JPO;	
			DERWENT;	:
			IBM_TDB	2002/06/02 18:36
-	1054	(257/355).CCLS.	USPAT; US-PGPUB;	2002/06/02 10.30
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/06/03 08:42
-	154	((("257/213").CCLS.) or (("257/327").CCLS.)	USPAT; US-PGPUB;	2002/06/03 06:42
		or (("257/335").CCLS.) or	EPO; JPO;	
		(("257/339").CCLS.) or	DERWENT;	
		(("257/355").CCLS.)) and buried.clm.	IBM_TDB	
_	71	((("257/213").CCLS.) or	USPAT; US-PGPUB;	2002/06/02 19:16
		(("257/288").CCLS.) or (("257/327").CCLS.) or (("257/335").CCLS.) or	EPO; JPO;	
		(("257/339").CCLS.) or	DERWENT;	
		(("257/355").CCLS.)) and buried.clm. and	IBM_TDB	
		switch\$3	HCDAE.	2002/06/02 19:37
-	4	((("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.)	USPAT; US-PGPUB;	2002/00/02 19:3/
		or (("257/335").CCLS.) or	EPO; JPO;	
		(("257/339").CCLS.) or	DERWENT;	
		(("257/355").CCLS.)) and buried.clm. and	IBM_TDB	
		(gate near4 connect\$3 near4 buried)	!	,2002/06/02 19:43
-	7	((("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.)	USPAT; US-PGPUB;	2002/00/02 19.45
		or (("257/335").CCLS.) or	EPO; JPO;	
	148	(("257/339").CCLS.) or	DERWENT;	
		(("257/355").CCLS.)) and buried adj	IBM_TDB	
		contact near3 gate	USPAT;	2002/06/02 19:45
-	1	dtmos and buried adj contact	US-PGPUB;	2002/00/02 13.43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/06/02 19:47
_	5	dtmos and buried near3 gate	USPAT; US-PGPUB;	2002/06/02 19.47
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/06/02 10:40
-		advantage and dtmos and buried near3 gate	DERWENT DERWENT	2002/06/02 19:48 2002/06/02 19:48
_	470 86	1	DERWENT	2002/06/02 19:48
	36	gate		
-	68	advantage and buried adj contact near6	DERWENT	2002/06/02 20:08
		gate	DEDMENT	2002/06/02 20:09
-	0	(buried or body) adj (contact or bias) near12 gate and dtmos	DERWENT	2002/00/02 20:09
_	0	(buried or body) adj (contact or bias)	DERWENT	2002/06/02 20:10
		near12 gate and 257/\$6.ccls.		1
-	195	(buried or body) adj (contact or bias)	DERWENT	2002/06/02 20:12
		near12 gate	HGDATT.	2002/06/02 20:40
-	939	(buried or body) adj (contact or bias) near12 gate	USPAT; DERWENT	2002/00/02 20.40
_	0		USPAT;	2002/06/02 20:27
		near12 gate and 5348714.pn.	DERWENT	
-	2	(buried or body) adj (contact or bias)	USPAT;	2002/06/02 20:27
		near12 gate and 6348714.pn.	DERWENT USPAT;	2002/06/02 20:40
1	416	(buried or body) adj (contact or bias)	DERWENT	2002,00,02 20.40
_	69		USPAT;	2002/06/02 21:16
		near3 connect\$3 near3 gate	DERWENT	

	561	(buried) adj (contact or bias) near3	USPAT;	2002/06/02 20:43
-	56	connect\$3 near3 gate	DERWENT	
	ا م	("5895939").PN.	USPAT;	2002/06/02 21:27
-	3	(2832333):114.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	_ '	parasitic adj capacitance near12 buried	USPAT;	2002/06/02 21:29
-	0	adj contact nearl2 (vertical adj field adj	US-PGPUB;	
		adj contact heariz (vertical adj riota adj	EPO; JPO;	
		effect or v-fet or v-igbt)	DERWENT;	
			IBM TDB	
			USPAT;	2002/06/02 21:44
-	1	parasitic adj capacitance near12 (vertical	US-PGPUB;	
		adj field adj effect or v-fet or v-igbt)	EPO; JPO;	
			DERWENT;	
			IBM TDB	1
			USPAT;	2002/06/02 22:26
-	134	t-gate.ti,ab.	US-PGPUB;	. 2002,00,00
			EPO; JPO;	i.
	1		DERWENT;	
			IBM_TDB	2002/06/02 21:45
_	0	t-gate.ti,ab. and buried near4 contact	USPAT;	2002/06/02 21:45
-		a gatarray	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	ļ
			IBM TDB	
		t-gate.ti,ab. and buried near6 contact	USPAT;	2002/06/02 21:45
_	0	t-gate.ti,ab. and builted heart to	US-PGPUB;	
			EPO; JPO;	ì
	ĺ		DERWENT;	
			IBM TDB	
		"in series"	USPAT;	2002/06/02 22:26
-	0	vertical adj DMOSFET near10 "in series"	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
		40 111	USPAT;	2002/06/02 22:2
_	0	vertical adj MOSFET near10 "in series"	US-PGPUB;	
			EPO; JPO;	
	ļ		DERWENT;	
			i	1
		10	IBM_TDB USPAT;	2002/06/02 22:2
_	0			, 2002/00/02 22.2
		"in series"	US-PGPUB;	
			EPO; JPO;	1
			DERWENT;	
			IBM_TDB	2002/06/02 22:4
_	1	(FET or transistor) near10 "in series"	USPAT;	2002/06/02 22:4
-	1	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
		(#C240714#\ PN	USPAT;	2002/06/02 22:4
-	2	2 ("6348714").PN.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	1		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	